

<b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b> (Use several sheets if necessary)  PTO Form 1449	Atty Docket No. 112857-315	Application No. 10/062,776
	Applicant Yoshiyuki Yanagisawa et al.	
	Filing Date 01/30/2002	Group 2812

U.S. PATENT DOCUMENTS						
Examiner's Initials	Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate
<i>[Handwritten Initials]</i>	5,177,405	01/05/1993	Kusuda et al.			
	5,206,749	04/27/1993	Zavracky et al.			
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Examiner's Initials	Document Number	Publication Date	Country	Class	Subclass	Translation	
						Yes	No
<i>[Handwritten Initials]</i>	56-17385	02/19/1981	Japan /				
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	57-45583	03/15/1982	Japan /				
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	6-45648	02/18/1994	Japan ✓				
	06-067044	03/11/1994	Japan ✓				
	06-504139	05/12/1994	Japan				

Examiner: <i>[Signature]</i>	Date Considered: <i>2/11/04</i>
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						Yes	No
<i>GM</i>	WO 95-05623	02/23/1995	PCT				
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11-514136	11/30/1999	Japan					

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Examiner's Initials	Document Number	Publication Date	Country	Class	Subclass	Translation	
						Yes	No
SM	11-346004	12/14/1999	Japan				
	2000-068593	03/03/2000	Japan ✓				
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SM	Zheleva et al., "Pendeo/Epitaxy - A New Approach For Lateral Growth Of Gallium Nitride Structures", MRS Internet J. Nitride Semicond. Res. 4S1, G3-38 (1999).
SM	Kapolnek et al., "Spatial Control Of InGaN Luminescence By MOCVD Selective Epitaxy, Journal Of Crystal Growth", 189/190 (1998) pp. 83/86.
SM	Applied Physics Letters, Vol. 76, Number 22, 29 May 2000, "Selective Growth Of InGaN Quantum Dot Structures And Their Microphotoluminescence At Room Temperature", Tachibani et al, pages 3212/3214

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